

# isc N-Channel MOSFET Transistor

# IPP60R280P7, IIPP60R280P7

### • FEATURES

- Static drain-source on-resistance:
   R<sub>DS</sub>(on) ≤0.28Ω
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

# DESCRIPTION

 Combines the benefits of a fast switching SJ MOSFET with excellent ease of use

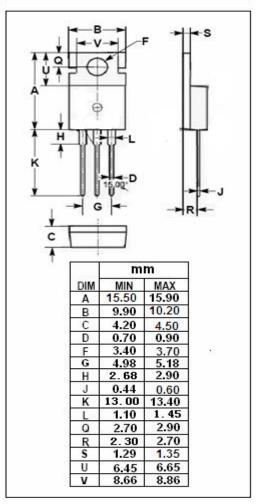
# pin 1, Gate 2, Drain 3, Source TO-220C package

# • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous 12		А	
I <sub>DM</sub>	Drain Current-Single Pulsed 36		А	
$P_D$	Total Dissipation @T <sub>C</sub> =25°C 53		W	
Tj	Max. Operating Junction Temperature 150		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

# • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.36	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W	





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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID =1mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =0.19mA	3		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; ID=3.8A			0.28	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =20V; V <sub>DS</sub> =0V			1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			1	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =3.8A; V <sub>GS</sub> = 0V		0.9		V

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